

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	304234	semiconductor and transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 13:06
L2	1	1 and (local\$4 thin\$4 fin)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	WITH	ON	2005/03/10 13:08
L3	0	1 and (local\$4 thin\$4 fin)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/03/10 13:08
L4	0	1 and (local\$4 thin\$4 fin)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	NEAR	ON	2005/03/10 13:09
L5	1	1 and (local\$4 thin\$4 fin)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	WITH	ON	2005/03/10 13:10
L6	0	1 and (local\$4 thin\$4 finfet)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	WITH	ON	2005/03/10 13:11
L7	247	1 and finfet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	WITH	ON	2005/03/10 13:12
L8	192	7 and thickness	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 13:12
L9	183	7 and thickness and etch\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 13:13

L10	23	9 and (gate with height with fin\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 13:16
L11	23	9 and (gate with height with fin\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/10 13:16